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Low Powered Diode Laser

Our low powered lasers deliver up to 55 mW of single mode laser power. Similar to our high power lasers, the low powered lasers have excellent frequency and intensity stability, and a long lifetime.



Specifications

Spatial Mode	• Single-Transverse.
Standard Wavelengths	• 670 nm, 785 nm, 808 nm, and 852 nm.
Polarization	Vertically polartized.
Wavelength Accuracy	• ± 0.1 nm
Wavelength Repeatability (ON/OFF)	• STD ~ 0.15 cm ⁻¹
Linewidth	• ~ 1 cm ⁻¹
Output Beam	• Free space (FS).
Power Output	• Typically 35-45 mW for 785 nm, 45-55 mW for 852nm
Power Monitor	Photodiode
Power Requirements	• 2.5 Amps min. at 12 VDC.
Estimated Lifetime	 > 9,000 hours (~ one year)
Warranty	• 5,000 hours for 785 nm and greater wavelengths.
Temperature Controlled	• Via Thermoelectric (TE) coolers.

Ambient Operating Temperature	 15-35°C (Thermal shutdown protection for over temperature.)
Environmental Protection	Laser diode and optics sealed
Dimensions	• 9.25" x 2.5" x 4.25" (23 cm x 6 cm x 11 cm)
Weight	• ~ 4.4 lbs. (2 kg)





Process Instruments Inc. | 630 S. Komas Drive #310 | Salt Lake City, Utah, 84108-

1229

Phone: (801) 322-1235(tel:1-801-322-1235) | Fax: (801) 322-5607

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